



SDI FINAL EVALUATION FORM 1.1

PART 1:

Journal Name:	Physical Science International Journal
Manuscript Number:	2015_PSIJ_18362
Title of the Manuscript:	Diffusion and trapping of positrons in unimplanted and ion-implanted 3C-SiC and 6H-SiC
Type of the Article	Original Research Article

PART 2:

FINAL EVALUATOR'S comments on revised paper (if any)	Authors' response to final evaluator's comments
It is suitable for being published now.	

Reviewer Details:

Name:	<i>Chaohui Zhang</i>
Department, University & Country	<i>Electronic and Control Engineering, Beijing Jiaotong University, China</i>